

SERVICE MANUAL

R-300 [Revised]



COMMUNICATIONS RECEIVER

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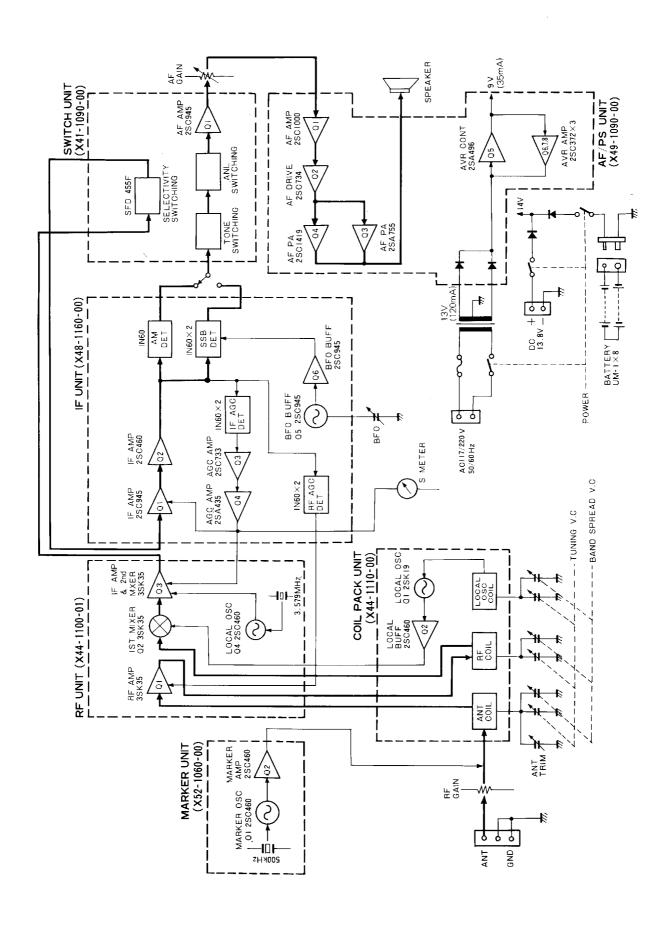
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• In this service manual, mark K shows the products to U.S.A., W does

to Europe for BCL, and W2 does to Europe for HAM.

SPECIFICATIONS

FREQUENCY RANGE	,	IF REJECTION
BAND A	170 ~ 410 kHz	BAND A 280 kHz More than 50 dB
BAND B	525 ~ 1250 kHz	BAND B 900 kHz More than 60 dB
BAND C	1.25 ~ 3.0 MHz	BAND C 2.0 MHz More than 70 dB
BAND D	3.0 ~ 7.5 MHz	BAND D 5.0 MHz More than 70 dB
BAND E	7.5 ~ 18.0 MHz	BAND E 12.0 MHz More than 70 dB
BAND F	18.0 ~ 30 MHz	BAND F 24.0 MHz More than 70 dB
BAND SPREAD		SELECTIVITY
(different depending or	n the destination area)	Narrow More than 2,5 kHz at -6 dB
Short Wave Bands:		Less than 12 kHz at -60 dB
75 m	3,82 ~ 4,0 MHz	Wide More than 5 kHz at -6 dB
60 m	4,75 ~ 5.1 MHz	Less than 17 kHz at -60 dB
49 m	5.9 ~ 6.2 MHz	
41 m	7.0 ~ 7.5 MHz	AUDIO OUTPUT
31 m	9.4 ~ 9.8 MHz	1.5W at 8Ω load (10% distortion)
25 m	11.7 ~ 12.0 MHz	
19 m	15.0 ~ 15.5 MHz	ANTENNA IMPEDANCE
16 m	17.6 ~ 18,0 MHz	50 ~ 75Ω
13 m	21.4 ~ 21.8 MHz	
11 m	25.6 ~ 26.2 MHz	AUDIO OUTPUT IMPEDANCE
Ham Bands:		4 to 8 ohms
80 m and 75 m	3.5 ~ 4.0 MHz	DOMED DECILIDEMENTS
40 m	7 ~ 7.5 MHz	POWER REQUIREMENTS
20 m	14 ~ 14.6 MHz	AC 117/220V
15 m	21 ~ 21.5 MHz	DC 12 ~ 16V (13.8V as reference)
10 m	28 ~ 30 MHz	POWER CONSUMPTION
MODE	AM, SSB, CW	
		8W (AC 117/220V)
SENSITIVITY	(S+N)/N, 10 dB at 50mW/8 Ω	4.1W (DC 13.8V)
	AM SSB	6.9W (DC 13.8V, LIGHT switch ON condition)
BAND A 280 kHz	Less than $1\mu V$ Less than $0.3\mu V$	SEMICONDUCTOR COMPLEMENT
BAND B 900 kHz	Less than $1\mu V$ Less than $0.3\mu V$	4 FET's
BAND C 2.0 MHz	Less than 1μV Less than 0.3μV	21 Transistors
BAND D 5.0 MHz	Less than $1.5\mu V$ Less than $0.5\mu V$	24 Diodes
BAND E 12.0 MHz	Less than 1.5µV Less than 0.5µV	
BAND F 24.0 MHz	Less than 1μV Less than 0.3μV	DIMENSIONS
IMAGE RATIO		W (362 mm) 14-1/4"
BAND A 280 kHz	More than 65 dB	H (163 mm) 6-7/16"
BAND B 900 kHz	More than 50 dB	D (322 mm) 12-11/16"
BAND C 2.0 MHz	More than 45 dB	
BAND D 5.0 MHz	More than 40 dB	WEIGHT
BAND E 12.0 MHz	More than 25 dB	WEIGHT
BAND F 24.0 MHz	More than 40 dB	7.6 kg (16.7 lbs.)

BLOCK DIAGRAM



FEATURES/CIRCUIT DESCRIPTION

FEATURES

- 1. This is a communications receiver exclusively designed for BCL and HAM radio.
- 2. In order to facilitate both fixed and mobile operation, it is designed to operate on the AC commercial source, internal battery, and external DC source.
- 3. A frequency range from 525 kHz to 30 MHz is continuously covered. Single conversion is effected for 525 kHz \sim 18 MHz, and double conversion for 18 MHz \sim 30 MHz.
- 4. AM, CW, and SSB reception is possible. A variable BFO incorporated is available for CW and SSB.
- 5. Selectivity is chosen by WIDE/NARROW selector switch. A ceramic filter is adopted.
- 6. With a built-in 500 kHz marker unit, scale correction is possible for every 500 kHz.
- 7. Recording in combination with a tape recorder is possible through RECORDING terminal.
- 8. The tuning dial employs a flywheel to improve operational feeling.
- 9. A 10cm speaker is incorporated. A terminal for an external speaker is also provided.
- Meter and dial lamps are always lit when operating on the AC source. In DC operation, they are lit only if LIGHT switch is depressed.

CIRCUIT DESCRIPTIONS

1. Configuration of R-300

R-300 is a all solid-state communications receiver for the reception of AM, CW, and SSB waves. The frequency range of 170 kHz \sim 30 MHz is divided into 6 bands. MOS type dual gate FET's 3SK35 are used for the RF amplifier and mixer. Employing double conversion arrangement for the F band, reception is very stable against cross modulation and image frequency interference.

The whole circuit is composed of a coil pack unit with a local oscillator, RF unit, IF unit, AF and stabilized source unit, and marker unit arranged into 5 printed circuit boards. The following descriptions are given according to the flow of signals in the block diagram.

2. RF Amplifier (RF unit and coil pack unit)

The antenna input passes through the RF and GAIN volume control and enters the antenna coil tap. In the antenna tuning circuit, the coil is split into sections for 6 bands and tuning is effected with main-tuning variable capacitor, band spread variable capacitor, and antenna trimmer. Input impedance ranges from 50 to 75 ohms.

The signal is received at the first gate of MOS type dual gate firld effect transistor (FET 3SK35), where high-frequency amplification is performed. FET 3SK35 has a small feed-back capacity of 0.02pF. Due to the effect of R₂, R₆, and R₈, the signal is amplified stably and fed to

the RF coil. AGC voltage taken out of the IF detector stage is applied to the second gate of 3SK35 for gain control

3. Diode Switch for Output Tuning Circuit Selection and Mixer (RF unit)

The signal from the RF amplifier is applied to the first gate of 3SK35 and mixed with the local oscillation signal of the second gate. The differential mixer output is converted into an IF signal of 455 kHz for the A \sim E bands, or into that of 4.034 MHz for the F band. The MOS type dual gate FET is stable against cross modulation due to excessive input or deviation by local oscillation. In particular it offers an excellent characteristic when used for a mixer.

Switching over between 455 kHz IFT and 4.034 MHz IFT is effected by the aid of a diode switch comprizing D1 \sim 4 and this switch is actuated in conjunction with the band selector switch. In 455 kHz setting for bands A \sim E, current from the 9V source flows through the 2 routes, R15 \rightarrow T1 \rightarrow D1 \rightarrow 3SK35 and R15 \rightarrow T1 \rightarrow D3 \rightarrow L1 \rightarrow R17. Thus D1 and D3 are turned on and the 455 kHz output is obtained through 3SK35 \rightarrow D1 \rightarrow T1 \rightarrow D3 \rightarrow C11. In setting for band F, D2 and D4 are turned on and the 4.034 MHz output is obtained through 3SK35 \rightarrow D2 \rightarrow T2 \rightarrow D4 \rightarrow C11.

4. Local Oscillator (coil pack)

In order to achieve stabilized oscillation in a wide frequency range from 625 kHz to 34.034 MHz, the local oscillator circuit of R-300 employs a Hartley circuit of drain-grounded FET 2SK19. To secure a stabilized oscillation of the F band, an oscillator circuit is incorporated in the coil pack. To reduce unwanted influence from the mixer circuit, an emitter-follower type buffer circuit of 2SC-460 is provided. The oscillating frequencies are 455 kHz higher than the received frequencies of the A \sim E bands, and 4.034 MHz higher than the received frequency of the F band, as specified below:

A $0.625 \sim 0.865 \text{ MHz}$ D $3.455 \sim 7.955 \text{ MHz}$ B $0.98 \sim 1.705 \text{ MHz}$ E $7.955 \sim 18.455 \text{ MHz}$ C $1.705 \sim 3.455 \text{ MHz}$ F $22.034 \sim 34.034 \text{ MHz}$

5. Second Mixer/IF AMP and F-band Conversion Crystal Oscillator (RF unit)

Signals converted into 455 kHz and 4.034 MHz enter the first gate of Q3 3SK35. This stage functions as an IF amplifier of 455 kHz for the A \sim E bands, while for the F band it functions as a 455 kHz mixer and the signal is mixed with a conversion signal of 3.579 MHz injected in the second gate. A mechanical filter is used for the output tuning circuit to obtain high selectivity.

Since the operating point of the 455 kHz IF amplifier

CIRCUIT DESCRIPTION

is different from the bias point of the second mixer, a diode switch of D5 and D6 is used for interlocked operation with the band switch. When used as an IF amplifier, no voltage is applied to D5 which is therefore turned off. This AGC voltage is applied through D6 for gain control. During operation as a second mixer, a voltage higher than AGC voltage is applied through D5 to FET as a fixed bias. At that time D6 is turned off and AGC voltage is not applied to the mixer.

Q4 2SC460 is a second local oscillator for the double conversion in the F band only. A 3.579 MHz crystal oscillator is employed in this circuit. Output from the output coil is divided by C18 and C19, and is supplied to the second gate of the second mixer.

6. IF Amplifier (IF unit)

The 455 kHz IF amplifier contains 2 amplifier stages of 2SC945. The first stage receives an AGC voltage for gain control. Selectivity for a signal is almost settled in the IF circuit. To obtain a required selectivity, R-300 employs an ON-OFF switch to add or remove the ceramic filter. Selectivity (6 dB band) is 5 kHz in WIDE and 2.5 kHz in NARROW setting.

7. AGC Amplifier (IF unit) and S Meter Orcuit

An IF signal from the collector of IF amplifier Q2 is applied to the voltage-double detector circuit of D6 and D7 through C15. This output is amplified at Q3 2SC733 and Q4 2SA495, and fed to the IF amplifier as AGC (automatic gain control) voltage. A signal from the collector of IF amplifier Q2 passes through C11 and is voltage-doubled and detected at D4 and D5. This output is applied to the Rf amplifier as AGC voltage so that the amplifier gain can be controlled in compliance with signal intensity. In the IF-AGC operation, the signal is detected at D6 and D7 and ①voltage is applied to the base of Q3. Since collector current flows in Q3 in compliance with the intensity of this voltage, collector voltage of Q3 (and also, base voltage of Q4) is lowered due to the effect of R14, thus resulting in a current flow in Q4. Therefore emitter voltage of Q4 (this is AGC voltage and is also used as bias voltage for the IF amplifier) is lowered to reduce the gain in IF amplifier.

In the RF·AGC operation, the signal is detected at D4 and D6 and the obtained \ominus voltage is applied to both ends of R3 which is connected in series with the second gate bias circuit of the RF amplifier. In this way, voltage of the second gate is lowered for gain control.

The S meter is used to measure IF-AGC voltage.

8. AM Detector Circuit and ANL (IF unit)

The AM signal is detected by the diode linear detector circuit. The signal taken from the collector circuit of $\Omega 2$ in the final IF stage passes through C9 and the \oplus side of

carrier frequency is deleted by diode D3. After passing through the filter consisting of C10 and R28, the obtained envelope is used as a low-frequency signal.

ANL (automatic noise limiter) employs a service diode to be inserted between detector output circuit and low-frequency amplifier. Noise is removed by this diode which is turned on and off by the effect of noise output.

9. CW/SSB Detector and BFO Circuit (IF unit)

The CW and SSB detection employs a balanced detector circuit. The CW/SSB signal supplied to T2 in the final IF stage is mixed with a BFO signal at the balanced detector circuit consisting of T2, D1, D2, R9, and R10, to make up an audio-frequency signal. The balanced detector circuit has a simple but efficient construction which never gives rise to saturation regardless of whether the signal intensity is strong or weak.

The BFO circuit si a base-grounded Colpitts oscillator with a special feature of high capacitance and low inductance. There is a sufficient stability in thermal and drift characteristics, particularly essential in SSB reception. An emitter-follower buffer is connected to the detector circuit for prevention of frequency draw-in and impedance matching. The BFO frequency is adjustable within the range of 455 kHz ±3 kHz by BFO pitch control.

10. AF Amplifier (AF/PS unit)

The detected audio-frequency signal passes through the AF-GAIN volume control, is amplified at the AF preamplifier of Q1 2SC1000, and enters the AF driver amplifier of Q2 2SC734. Since a push-pull type power amplifier is driven, the collector circuit of Q2 is somewhat complicated. D4 and D5 are used to give a proper bias to Q3 and Q4. Thus an equivalent load resistance is raised to increase the amplification degree of Q2 by the aid of the effect of R10, R11, and C9.

The power amplifier is a so-called complementary OTL which performs series operation of NPN and PNP transistors in terms of DC, and parallel operation in terms of AC. The bases of Q3 and Q4 receive audio-frequency signals in the same phase. Thus, Q4 operates on the \oplus side of the signal and Q3 operates on the \ominus side in a push-pull mode.

11. 9V Stabilized Source (AF/PS unit)

In order to increase operational stability in R-300, all circuits except for the AF power amplifier operate on the 9V stabilized power supply. Voltage of $10 \sim 16 \text{V}$ is applied to the emitter of 0.5 and a 9V output voltage is obtainable from the collector. If this output voltage deviates from 9V for a certain reason, a voltage deviation component is detected by the error voltage detector circuit consisting of 6V zener diode and a differential amplifier of $0.7 \approx 0.00$ and 0.00 This component is amplified at $0.00 \approx 0.00$

CIRCUIT DESCRIPTION

base of Q5 in the direction of canceling an output voltage deviation from 9V, thus always maintaining voltage at 9V. VR1 is a volume control for setting the output voltage to 9V. This circuit also functions as a protective circuit to suppress an overcurrent possibly caused by a short-circuit failure in the 9V output circuit.

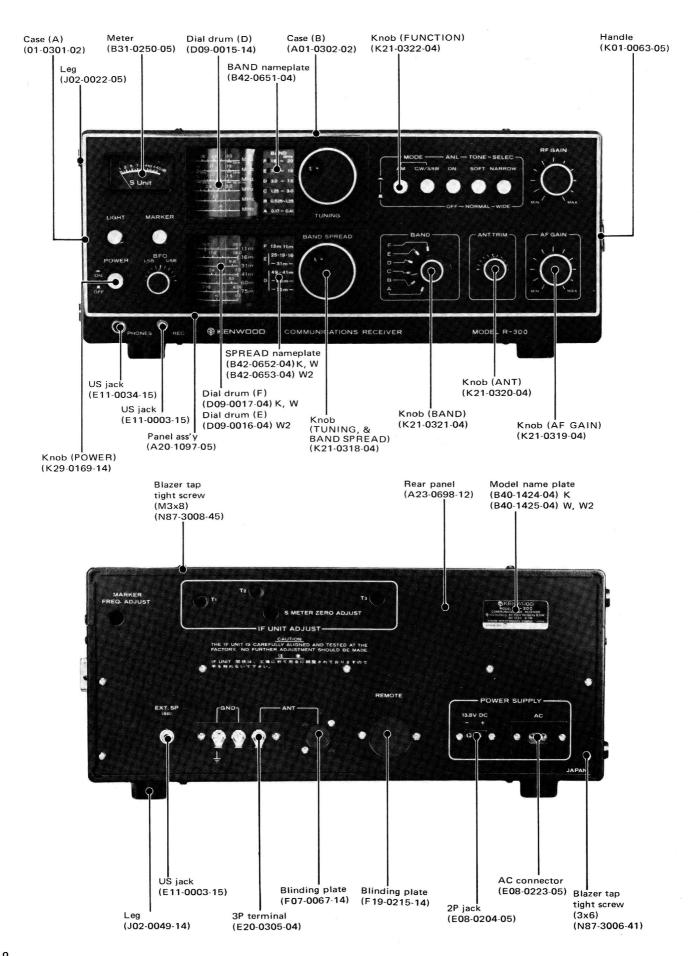
12. Power Circuit and Pilot Lamp Circuit

A step-down power transformer receives power from an AC 100V power source and lowered voltage is fullwave rectified at D1 and D2 of the AF/PS unit. The power supply of $14 \sim 14.5 \text{V}$ is then fed to the AF power amplifier and the stabilized power supply circuit. Diodes D1, D2, and D3 in the internal battery circuit, external DC circuit, and B-power supply line are used to prevent the occurrence of short-circuit failure in the power line and for automatic switching over between AC and DC. If an internal battery

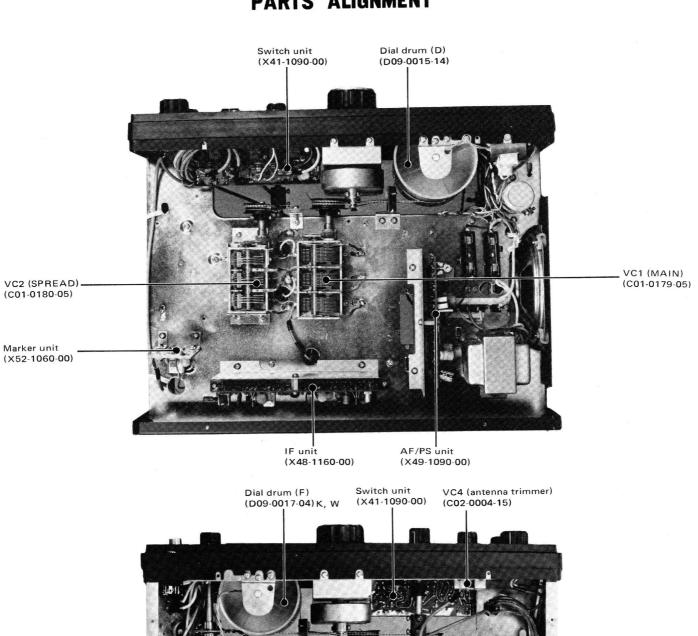
is connected and the set is actuated on the AC source, 14V is applied to the ® side of D1 and 12V to the ® side. Thus D1 is turned off due to reverse bias and current does not flow from the battery circuit. If the AC cord is pulled out of the AC source circuit or service interruption occurs, voltage at point ® disappears and D1 is turned on. In this state the set is actuated on the 12V supply from the internal battery circuit.

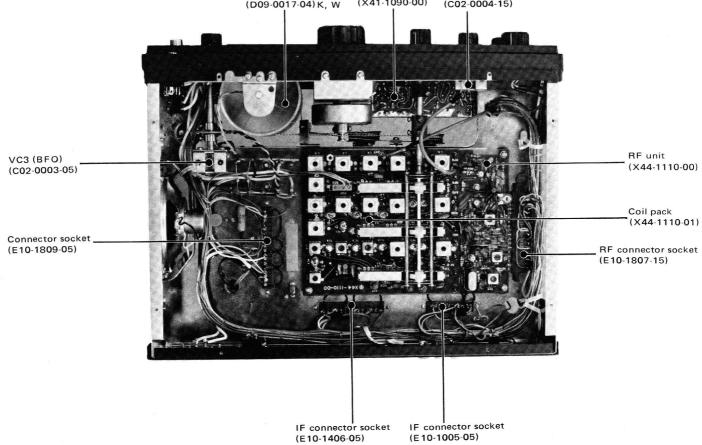
Pilot lamps are used for S meter and dial illumination. Since current for the lamps is larger than that to be consumed in the circuits, the lamps are lit only if the associated switch is turned on during operation on battery source. When operated on the external source, these lamps are lit through D2 at normal voltage. However, in operation on the internal battery source, the lamps are lit through R1 to reduce battery consumption by maintaining current at the lowest permissible level.

PARTS ALIGNMENT



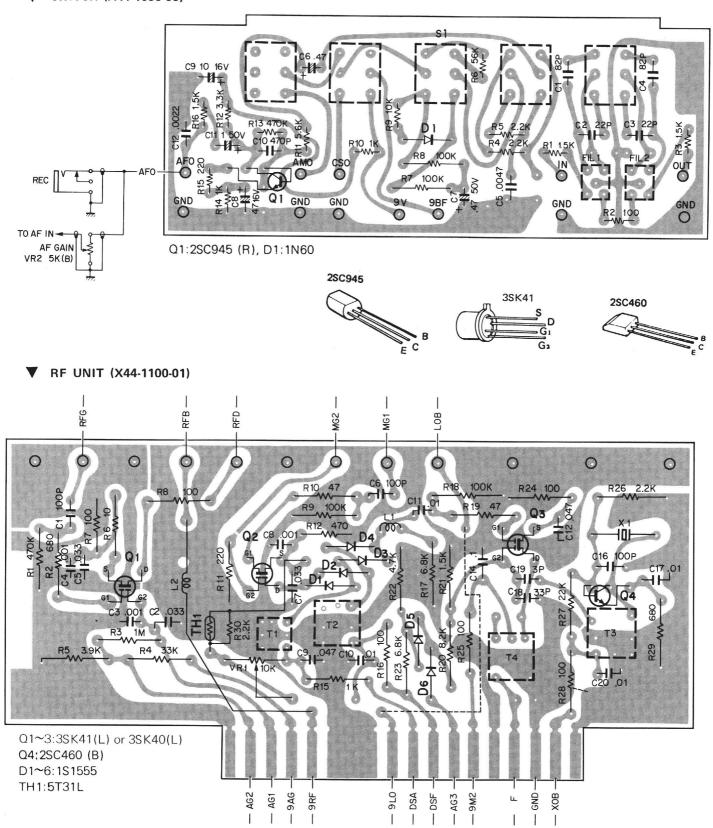
PARTS ALIGNMENT





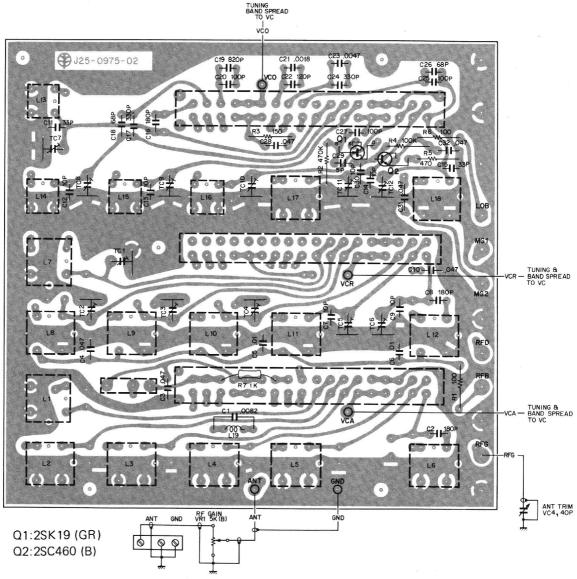
PRINTED BOARD

▼ SWITCH (X41-1090-00)

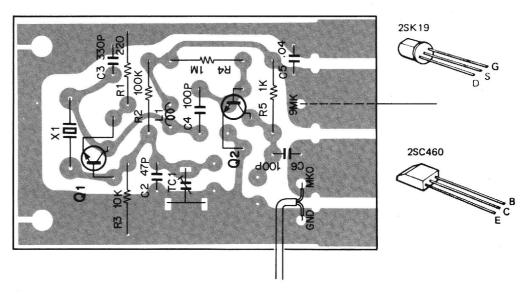


PRINTED BOARD

▼ COIL PACK (X44-1110-00)

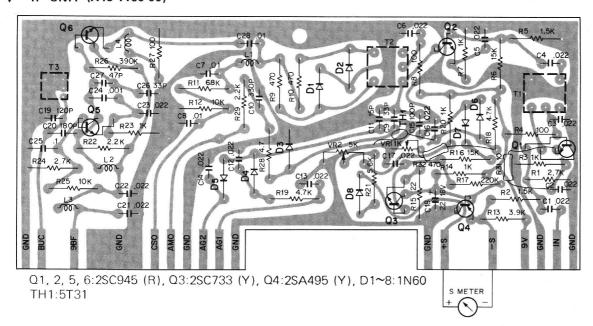


MARKER (X52-1060-00)

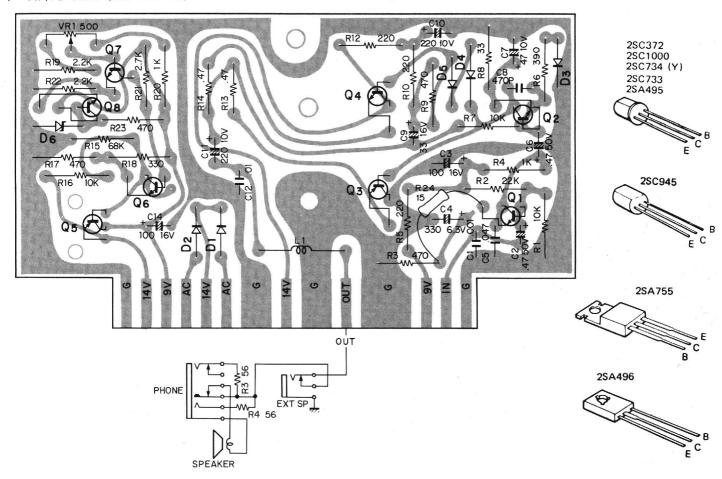


PRINTED BOARD

▼ IF UNIT (X48-1160-00)



▼ AF/PS UNIT (X49-1090-00)



Q1:2SC1000 (BL), Q2:2SC734 (Y), Q3:2SA755 (C), Q4:2SC1419 (C), Q5:2SA496 (Y), Q6~8:2SC372 (Y), D1, 2, 4, 5:V06B, D3:1S1555, D6:WZ-061

TOTAL			-	. Europe i	OI TIANI dad		
Ref. No.	Parts No.	Description	Re- marks	Ref. No.	Parts No.	Description	Re- marks
		CAPACITOR		-	E10-1807-15	Connector socket (RF)	
C1	C90-0207-05	Electrolytic 3300µF 25WV		-	E10-1809-05	Connector socket	
C2	CE04W1H010(RL)	Electrolytic 3300µF 25WV		-	E11-0003-15	US jack (for EXT SP) x 2	
C3	CK45E3D103P	Ceramic 0.01µF +100%,—0%		-	E11-0034-15	US jack	
	CK45E3D TQ31	Ceramic 0.01µF +100%,-0%		-	E20-0305-04	Terminal (3P)	
		RESISTOR		-	E20-0509-05	T type lug	
R1	RN14AB3G220K	Metal film 22Ω ±10% 4W	1	-	E22-0105-04	Lug	
R3, 4	PD14BY2E560J	Carbon $56\Omega \pm 5\% 1/4W$		-	E22-0207-04	Lug	
		5022 ±5% 1/44V		-	E22-0305-05	Lug	
	SE	MICONDUCTOR		-	E22-0404-05	Lug x 2	
D1~3	V11-0219-05	Diode V06B		-	E23-0015-04	Earth lug x 2	
			<u> </u>	-	E30-0244-05 E30-0245-05	Lead wire x 2 Lead wire	
	PC	PTENTIOMETER		1_	E30-0321-05	AC cord	W,W2
VR1, 2	R03-2033-05	Semiconduct 5k Ω (B)	ជ	_	E30-0584-05	AC cord	κ
				_	E31-0401-05	Lead wire	
VC1	C01-0179-05	Variable capacitor (Main)		· _	E31-0402-15	Lead wire	
VC2	C01-0180-05	Variable capacitor (Spread)		I_	E33-0086-00	Wire kit	K☆
VC3	C02-0003-05	Midget variable capacitor (BFO)	☆	1_	E33-0087-00	Wire kit	K☆
VC4	C02-0004-15	Midget variable capacitor	û	1_	E33-0088-00	Wire kit	W☆
		(Antenna trimmer)		-	E33-0089-00	Wire kit	W☆
	141	COELL ANEOUG	-	1_	E33-0607-00	Wire kit	W2☆
	MI	SCELLANEOUS		_	E33-0608-00	Wire kit	W2☆
_	A01-0301-02	Case (A) (Under)	☆	1			
	A01-0302-02	Case (B) (Upper)	☆	l_	F05-1521-05	Fuse 1.5A	
-	A10-0372-31	Chassis		1_	F05-2012-05	Fuse 0.2A	K
_	A20-1097-05	Panel ass'y	☆	1_	F05-8002-05	Fuse 80mAT	W,W2
-	A20-1098-05	Panel	☆	1_	F07-0067-14	Blinding plate	,
-	A22-0202-42	Sub panel	ŵ	<u> </u> _	F09-0026-05	Battery case x 2	
-	A23-0698-12	Rear panel	☆	_	F09-0033-05	Capacitor cover	
-	A25-0005-23	Buffle .		I_	F10-0325-14	IF shield plate	
				l_	F10-0325-14	AF shield plate	
- 1	B05-0204-04	Speaker grille cloth		 _	F15-0212-24	Band mask	☆
-	B09-0003-05	Shaft joint		_	F19-0215-14	Blinding plate	☆
-	B10-0213-04	Front glass	û	1_	F19-0216-04	Back cover	☆
	B21-0011-24	Pointer	☆	_	F20-0084-04	Insulating plate (for terminal)	
[_	B30-0079-05	Pilot lamp 12V 40mA x 2	☆	1_	F20-0085-04	Insulating plate (for coil pack)	
_	B31-0250-05	Pilot lamp (Meter)	☆		1 20 0000 04	modulating place (10) con pack,	
		with B30-0085-15		1_	G01-0044-14	Dial spring x 2	
_	B40-1424-04	Name plate (Model)	άK	1_	G01-0349-04	Coil spring	☆
_	B40-1425-04	Name plate (Model)		_	G10-0601-04	Felt for speaker	쇼
_	B41-0211-04	Name plate (Fuse)	W, W2	ļ_	G13-0014-04	Vibration protector (rubber) x 8	
-	B42-0458-04	Name plate (Adjusting)	,	1	G13-0082-04	Cushion rubber x 4	
_	B42-0651-04	Name plate (Band)	☆	1	G13-0601-04	Cushion x 4	ជ
_	B42-0652-04	Name plate (Spread A)	κ,w	-	313-0001-04	Gusinon x 4	
_	B42-0653-04	Name plate (Spread B)	w ₂		H01-1607-04	Case (Inside)	☆
_	B46-0058-00	Warranty card	ĸ		H03-0536-04	Case (Miside)	☆
_	B50-1557-00	Operating manual			H10-1123-02	Styrene foam cushion (B)	"
				-		Styrene foam cushion (A)	☆
_	D09-0015-14	Dial drum (D)	☆	-	H10-1459-02	Packing material, foamed styrene	쇼
_	D09-0016-04	Dial drum (E)	έW2		H12-0401-04 H20-0381-14	Protection cover	
l	D09-0017-04	Dial drum (F)	άK,W	-	H25-0007-04	Protection cover	
	D15-0083-14	Pulley x 2	,,,,			Protection bag Protection bag (Large)	
	D15-0160-04	Pulley (Small) x 5		Į ⁻	H25-0103-03	Trotaction bay (Large)	
_	D15-0167-03	Dial pulley x 2	☆		102-0022-05	Leg x 4	
_	D15-0701-04	Pulley	☆	_	J02-0022-05		
_	D21-0331-24	Drive shaft (for Drum)		-	J02-0049-14	Leg x 4	K
_	D21-0333-24	Druve shaft (for BFO)		_	J13-0019-05	Fuse holder	W,W2
_	D21-0425-14	Band shaft	슙	-	J13-0027-05	Fuse holder Fuse holder (DC code)	VV,VVZ
	D22-0004-04	Shaft coupler		-	J13-0029-05		☆
_	D23-0061-04	Bearing (BFO)		-	J19-0498-14	Meter holder	ਸ ਜ਼
_	D23-0117-04	Bearing (Band)		-	J19-0499-04	Lamp holder (Upper)	ਸ ਜ਼ੈ
_	D40-0213-03	Dial pulley ass'y		-	J19-0500-04	Lamp holder (Under)	"
}				-	J21-0047-04	Marker mounting hardware x 2	
_	E08-0203-25	Connector jack (2P)			J21-0392-04	Lead holder x 3	
_	E08-0204-05	Consent jack (2P)		-	J21-1173-04	VC fitting (A) (Spread back)	}
_	E08-0223-05	AC connector			J21-1174-04	VC fitting (B) (Spread front)	
_	E09-0203-25	Connector plug (2P)		-	J21-1175-14	VC fitting (C) (BFO)	
_	E03-0204-05	Consent plug (2P)		-	J21-1571-24	Drum fitting x 2	Ω
_ 1	E09-0314-05	Mini connector		-	J21-1573-04	Small pulley stopper (A)	\ \text{\tin}\text{\tetx}\\ \text{\text{\text{\text{\text{\text{\text{\text{\text{\texi}\\ \text{\tetx}\\ \ti}}\\ \text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\texi}\text{\text{\texi}\text{\text{\text{\text{\text{\text{\text{\texi}\text{\text{\texi}
_	E10-1005-05	Connector socket (IF)		j-	J21-1574-14	Small pulley stopper (B) x 3	tì tì
_	E10-1406-05			-	J30-0061-04	Rubber spacer x 4	
-	E 10-1400-03	Connector socket (IF)		_	J32-0117-04	Hexagonal boss x 2	

Ref. No.	Parts No.	Description	Re- marks
_	J32-0133-04	Hexagonal boss x 8	
_	J32-0229-14	Hexagonal boss	☆
_	J39-0049-14	Spacer	☆
_	J59-0001-05	Plunger x 4	
_	J59-0002-05	Grommet x 4	
_	J61-0019-05	Vinyl tigh	1
_	J90-0079-04	Pointer shaft	ជ
_	K01-0063-05	Handle	☆
_	K21-0318-04	Knob (Tuning, Band spread) x 2	☆
_	K21-0319-04	Knob (RF, AF GAIN) x 2	ά
	K21-0320-04	Knob (ANT, BFO) x 2	☆
-	K21-0321-04	Knob (BAND)	☆
_	K21-0322-24	Knob (Function, Marker, Light) x 7	☆
_	K29-0169-14	Knob (Power)	
_	L09-0001-45	Power transformer	
_	\$40-2039-05	Push switch (With lock)	
_	S40-2040-05	Push switch (Non lock)	
_	S40-4015-05	Push switch (Power)	
-	T05-0006-25	Speaker	
_	X41-1090-00	Switch unit	☆
	X44-1100-01	RF unit	ជ
-	X44-1110-00	Coil pack	
_	X48-1160-00	IF unit	☆
_	X49-1090-00	AF/PS unit	☆
-	X52-1060-00	Marker unit	

Ref. No.	Parts No.	Description	Re- marks			
MISCELLANEOUS						
S1	S42-5008-05	Push switch	益			
_	E23-0047-04	Terminal (Square) x 12				

Ref. No.	Parts No.		Descrip	tion		Re- marks
		CAPACIT	OR			
C1	CC45CH1H101J	Ceramic	100pF	± 5%		
C2	CQ92M1H333K	Mylar	0.033μF	± 10%		
C3, 4	CK45D1H102M	Ceramic	$0.001 \mu F$	± 20%		
C5	CQ92M1H333K	Mylar	0.033µF	± 10%		
C6	CC45CH1H101J	Ceramic	100pF	±5%		
C7	CQ92M1H333K	Mylar	0.033µF	± 10%		
C8	CK45D1H102M	Ceramic	0.001µF	±20%		
C9	CQ92M1H473K	Mylar	0.047µF	± 10%		
C10, 11	CQ92M1H103K	Mylar	0.01µF	± 10%		
C12	CQ92M1H473K	Mylar	0.047µF	± 10%		
C14	CQ92M1H104K	Mylar	$0.1 \mu F$	± 10%		
C16	CC45CH1H101J	Ceramic	100pF	± 5%		
C17	CQ92M1H103K	Mylar	0.01µF	± 10%		
C18	CC45CH1H330J	Ceramic	33pF	± 5%		
C19	CC45CH1H030D	Ceramic	3pF	±0.5p	F	
C20	CQ92M1H103K	Mylar	0.01µF	± 10%		
		RESIST	OR			
R1	PD14BY2E474J	Carbon	470kΩ	±5%	1/4W	
R2	PD14BY2E681J	Carbon	Ω 086	± 5%	1/4W	
I .	1	1		. = 0/	4 / 4141	1

R3 PD14BY2E105J Carbon $1M\Omega$ ±5% 1/4W $33k\Omega$ ± 5% 1/4W PD14BY2E333J Carbon R4 1/4W R5 PD14BY2E392J Carbon $3.9 k\Omega$ ± 5% 1/4W 10Ω ± 5% R6 PD14BY2E100J Carbon 1/4W R7, 8 PD148Y2E101J Carbon 100Ω ± 5% Carbon 100k Ω ±5% 1/4W R9 PD14BY2E104J 47Ω ±5% 1/4W Carbon PD14BY2E470J R10 220Ω 1/4W Carbon ± 5% R11 PD14BY2E221J 1/4W R12 PD14BY2E471J Carbon 470Ω ±5% R15 PD14BY2E102J Carbon 1kΩ ± 5% 1/4W 100Ω ±5% 1/4W Carbon R16 PD14BY2E101J $6.8k\Omega$ ±5% 1/4W R17 PD14BY2E682J Carbon 100k Ω ± 5% 1/4W R18 PD14BY2E104J Carbon PD14BY2E470J Carbon 47Ω ± 5% 1/4W R19 R20 Carbon 8.2 $k\Omega$ ± 5% 1/4W PD14BY2E822J 1/4W $1.5k\Omega$ ±5% Carbon R21 PD14BY2E152J ±5% R22 PD14BY2E472J Carbon $4.7k\Omega$ 1/4W R23 PD14BY2E682J Carbon $6.8k\Omega$ ±5% 1/4W 100 Ω ±5% 1/4W Carbon R24, 25 PD14BY2E101J $2.2k\Omega$ ± 5% 1/4W Carbon **R26** PD14BY2E222J R27 PD14BY2E223J Carbon $22k\Omega$ ±5% 1/4W Carbon 100 Ω ±5% 1/4W **R28** PD14BY2E101J 680Ω ± 5% 1/4W PD14BY2E681J Carbon **R29** ±5% 1/4W Carbon $2.2k\Omega$ R30 PD14BY2E222J **SEMICONDUCTOR**

Q1,2,3	V09-0057-05	FET 3SK41(L) or 3SK40(L)	-
Q4	∨0 3-0079-05	Transistor 2SC460 (B)	
D1~6	V11-0076-05	Diode 1S1555	
	F	POTENTIOMETER	
VR1	R12-3022-05	10kΩ (B)	
		COIL/CRYSTAL	
L1	L40-4725-04	Ferri-inductor 4.7 mH	
L2	L40-1021-03	Ferri-inductor 4.7 mH	
T1	L30-0288-05	IFT	☆
T2	L30-0267-05	IFT	☆

SWITCH (X41-1090-00)

Ref. No.	Parts No.	Description	Re- marks				
CAPACITOR							
C1	CC45CH1H820J	Ceramic 82pF ±5%					
C2, 3	CC45CH1H220J	Ceramic 22pF ±5%					
C4	CC45CH1H820J	Ceramic 82pF ±5%					
C5	CQ92M1H472K	Mylar $0.0047 \mu F \pm 10\%$					
C6,7	CE04W1HR47	Electrolytic 0.47µF 50WV					
C8	CE04W1C470	Electrolytic 47μF 16WV					
C9	CE04W1C100	Electrolytic 10µF 16WV	1				
C10	CK45B1H471K	Ceramic 470pF ±10%					
C11	CE04W1H010	Electrolytic 1µF 50WV					
C12	CQ92M1H222K	Mylar 0.0022μF ± 10%					
		RESISTOR					
R1	PD14CY2E152J	Carbon 1.5kΩ ±5% 1/4W					
R2	PD14CY2E101J	Carbon 100 Ω ±5% 1/4W					
R3	PD14CY2E152J	Carbon 1.5k Ω ±5% 1/4W					
R4, 5	PD14CY2E222J	Carbon 2.2k Ω ±5% 1/4W					
R6	PD14CY2E563J	Carbon 56k Ω ±5% 1/4W					
R7, 8	PD14BY2E104J	Carbon 100k Ω ±5% 1/4W					
R9	PD14CY2E103J	Carbon 10k Ω ±5% 1/4W					
R10	PD14CY2E102J	Carbon 1k Ω ±5% 1/4W					
R11	PD14CY2E562J	Carbon 5.6k Ω ±5% 1/4W					
R12	PD14CY2E332J	Carbon 3.3kΩ ±5% 1/4W					
R13	PD14CY2E474J	Carbon 470kΩ ±5% 1/4W					
R14	PD14CY2E102J	Carbon 1k Ω ±5% 1/4W					
R15	PD14CY2E221J	Carbon 220 Ω ±5% 1/4W					
R16	PD14CY2E152J	Carbon 1.5kΩ ±5% 1/4W	<u> </u>				
	SE	MICONDUCTOR					
Q1	V03-0270-05	Transistor 2SC945 (R)					
D1	V11-0051-05	Diode 1N60					
Fil 1, 2	L72-0042-05	Ceramic filter SED455F	☆				

Ref. No.	Parts No.	Description	Re- marks
Т3	L32-0167-05	OSC coil	핚
Т4	L30-0293-05	IFT	
X1	L77- 0 365-05	Quartz crystal (3.579 MHz)	☆
тн1	V22-0022-05	Thermistor 5T31L	
_	E06-0406-05	Transistor socket	
-	E23-0046-04	Terminal x 12	

	Ref. No.	Parts No.	Description	Re- marks			
	L14	L32-0169-05	OSC coil OSC B	ជ			
	L15	L32-0170-05	OSC coil OSC C	ú			
	L16	_16 L32-0171-05 OSC coil OSC D					
	L17	L32-0172-05	OSC coil OSC E	垃			
	L18	L32-0173-05	OSC coil OSC F	ជ			
	L19	L40-1501-03 Ferri-inductor 15µH					
	TRIMMER						
ļ	TC1~7	C05-0013-15	Trimmer capacitor 20pF				
	TC8~12	C05-0010-15	Trimmer capacitor 10pF				
		MIS	CELLANEOUS				
	_	E23-0046-04	Terminal (Square) x 5				
	_	E40-0371-05	Mini-connector				
		S29-3005-05	Rotary switch	☆			

COIL PAG	CK (X44-1110-00)	
Ref. No.	Parts No.	Description	Re- marks
	C	APACITOR	
C1	CQ93M1H822J	Mylar 0.0082μF±5%	
C2	CC45PH1H181J	Ceramic 180pF ±5%	i
C3,4	CQ92M1H473K	Mylar $0.047 \mu F \pm 10\%$	l
C5,6	CQ92M1H103K	Mylar 0.01μF ± 10%	
C7	CC45CH1H100D	Ceramic 10pF ±0.5pF	
C8	CC45PH1H181J	Ceramic 180pF ±5%	
C9	CC45CH1H100D	Ceramic 10pF ±0.5pF	
C10	CQ92M1H473K	Mylar 0.047μF ± 10%	
C11	CC45CH1H330J	Ceramic 33pF ±5%	
C12~14	CC45CH1H100D	Ceramic 10pF ±0.5pF	1
C15	CC45CH1H330J	Ceramic 33pF ±5%	
C16	CC45PH1H181J	Ceramic 180pF ±5%	
C17	CQ09S1H331J	Polystyrene 330pF ±5%	
C18	CC45PH1H680J	Ceramic 68pF ±5%	
C19	CQ09S1H821J	Polystyrene 820pF ±5%	
C20	CC45PH1H101J	Ceramic 100pF ±5%	
C21	CQ09S1H182J	Polystyrene 0.0018µF±5%	
C22	CC45PH1H121J	Ceramic 120pF ±5%	
C23	CQ09S1H472J	Polystyrene 0.0047µF±5%	
C24	CQ09S1H331J	Polystyrene 330pF ±5%	
C25	CC45PH1H101J	Ceramic 100pF ±5%	
C26	CC45PH1H680J	Ceramic 68pF ±5%	
C27	CC45CH1H101J	Ceramic 100pF ±5%	
C28	CQ92M1H473K	Mylar 0.047μF ±10%	
C29	CC45CH1H050D	Ceramic 5pF ±0.5pF	
C30	CC45CH1H100D	Ceramic 10pF ±0.5pF	
C31,32	CQ92M1H473K	Mylar 0.047μF ± 10%	
,	R	ESISTOR	
R1	PD14BY2E101J	Carbon 100 Ω ±5% 1/4W	
R2	PD14BY2E474J	Carbon 470k Ω ±5% 1/4W	
R3	PD14BY2E151J	Carbon 150 Ω ±5% 1/4W	
R4	PD14BY2E104J	Carbon 100k Ω ±5% 1/4W	
R5	PD14BY2E471J	Carbon 470 Ω ±5% 1/4W	
R6	PD14BY2E101J	Carbon 100 Ω ±5% 1/4W	
R7	PD14BY2E102J	Carbon $1k\Omega$ ±5% 1/4W	
	SEMI	CONDUCTOR	
Q1 Q2	V09-0012-05 V03-0079-05	FET 2SK19 (GR) Transistor 2SC460 (B)	
	V03-0079-05		
L1	L31-0326-05	COIL Tuning coil ANT A	
L2	L31-0325-05	•	습
L3	1	Tuning coil ANT B Tuning coil ANT C	쑈
L4	L31-0328-05 L31-0329-05	Tuning coil ANT C	ъ ф
L5	L31-0330-05	Tuning coil ANT E	☆
L6	L34-0566-05	Tuning coil ANT F	쇼
L7	L31-0332-05	Tuning coil ANT F	ਸ ਖ਼ੈ
L8	L31-0333-05	Tuning coil RF B	и ф
L9	L31-0333-05	-	и ф
L10	L31-0335-05	-	효
L10 L11	L31-0336-05	Tuning coil RF D Tuning coil RF E	ਸ ☆
L12	L31-0336-05 L31-0337-05	Tuning coil RF F	տ և
L12 L13	L32-0168-05	OSC coil OSC A	☆
- 10	-02-0100-00	300 con 030 A	н

IF (X48-1160-00)

Ref. No.	Parts No.		Descrip	otion	Re- marks		
CAPACITOR							
C1, 2	CQ92M1H223K	Mylar	0.022μF				
C3	CK45F1H223Z	Ceramic	0.022μF	+80%,-20%	i		
C4, 5	CQ92M1H223K	Mylar	0.022μF				
C6	CK45F1H223Z	Ceramic	$0.022 \mu F$	+80%,-20%			
C7, 8	CK45F1H103Z	Ceramic	$0.001 \mu F$	+80%,-20%			
C9	CC45CH1H330J	Ceramic	33pF	±5%			
C10	CK45B1H331K	Ceramic	330pF	± 10%			
C11	CC45CH1H150J	Ceramic	15pF	± 5%	1.		
C12~14	CK45F1H223Z	Ceramic		+80%,-20%			
C15	CC45CH1H101J	Ceramic	100pF	± 5%			
C16, 17	CK45F1H223Z	Ceramic	$0.022 \mu F$	+80%,-20%			
C18	CE04W1C220	Electroly	tic 22µF	16WV	ì		
C19	CC45SH1H121J	Ceramic	12 0 pF	± 5%			
C20	CC45PH1H181J	Ceramic	18 0 pF	±5%			
C21, 22	CK45F1H223Z	Ceramic	0 .022μF	+80%,-20%			
C23	CC92M1H223K	Mylar	0.022μF	± 10%			
C24	CQ92M1H102K	Mylar	0.001μF	± 10%			
C25	CQ92M1H104K	Mylar	0.1μ F	± 10%			
C26	CC45CH1H330J	Ceramic	33pF	± 5%			
C27	CC45CH1H470J	Ceramic	47pF	± 5%			
C28	CQ92M1H103K	Mylar	0.01μF	± 10%			
		RESISTO	R				
R1	PD14BY2E272J	Carbon	$2.7k\Omega$	±5% 1/4W			
R2	PD14BY2E152J	Carbon	1.5k Ω	±5% 1/4W			
R3	PD14BY2E102J	Carbon	1kΩ	±5% 1/4W			
R4	PD14BY2E101J	Carbon	100 Ω	±5% 1/4W			
R5	PD14BY2E152J	Carbon	1.5k Ω	±5% 1/4W			
R6	PD14BY2E153J	Carbon	15k Ω	±5% 1/4W			
R7	PD14BY2E102J	Carbon	1kΩ	±5% 1/4W			
R8	PD14BY2E101J	Carbon	100 Ω	±5% 1/4W			
R9, 10	PD14BY2E471J	Carbon	470 Ω	±5% 1/4W			
R11	PD14BY2E682J	Carbon	68 k Ω	±5% 1/4W			
R12	PD14BY2E103J	Carbon	10k Ω	±5% 1/4W			
R13	PD14BY2E392J	Carbon	3.9 k Ω	±5% 1/4W			
R14	PD14BY2E102J	Carbon	1kΩ	±5% 1/4W			
R15	PD14BY2E220J	Carbon	22Ω	±5% 1/4W			
R16	PD14BY2E153J	Carbon	15k Ω	±5% 1/4W			
R17	PD14BY2E224J	Carbon	220k Ω	±5% 1/4W			
R18	PD14BY2E472J	Carbon	4.7k Ω	±5% 1/4W			
R19	PD14BY2E472J	Carbon	4.7k Ω	±5% 1/4W			
R20	PD14BY2E102J	Carbon	1kΩ	± 5% 1/4W			
R21	PD14BY2E562J	Carbon	5.6k Ω	±5% 1/4W			
R22	PD14BY2E222J	Carbon	2.2k Ω	±5% 1/4W			
R23	PD14BY2E102J	Carbon	1kΩ	±5% 1/4W			
R24	PD14BY2E272J	Carbon	2.7k Ω	± 5% 1/4W			
R25	PD14BY2E103J	Carbon	10k Ω	±5% 1/4W			
R26	PD14BY2E394J	Carbon	39 0 kΩ	±5% 1/4W			

Ref. No.	Parts No.	Description	Re- marks
R27	PD14BY2E101J	Carbon 100 Ω ±5% 1/4W	
R28	PD14BY2E472J	Carbon 4.7k Ω ±5% 1/4W	
R29	PD14BY2E222J	Carbon 2.2k Ω ±5% 1/4W	
R31	PD14BY2E100J	Carbon 10 Ω ±5% 1/4W	
R32	PD14BY2E471J	Carbon 470 Ω ±5% 1/4W	
	SEM	ICONDUCTOR	
Q1, 2	V03-0270-05	Transistor 2SC945 (R)	
Q3	V03-0129-05	Transistor 2SC733 (Y)	ł
Q4	V01-0037-05	Transistor 2SA495 (Y)	
Q5, 6	V03-0270-05	Transistor 2SC945 (R)	1
D1~8	V11-0051-05	Diode 1N60	
TH1	V22-0013-05	Thermistor 5T31	
	РОТ	ENTIOMETER	
VR1	R12-1024-05	Semi-fixed 1kΩ	
VR2	R12-2014-05	Semi-fixed 5kΩ	
		COIL	
L1	L40-4725-04	Ferri-inductor	
L2	L40-6825-04	Ferri-inductor	
L3, 4	L40-2225-04	Ferri-inductor	
	•	TRIMMER	
T1, 2	L30-0293-05	IFT	☆
Т3	L32-0202-05	OSC coil	ជ

Ref. No.	Parts No.	Description				Re- marks	
R23	PD14BY2E471J	Carbon 4	470Ω	± 5%	1/4W		
R24	PD14BY2E150J	Carbon '	15Ω	±5%	1/4W		
	SE	MICONDUC	TOR				
Q1	V03-0279-05	Transistor	2SC1	000 (BL)		
Q2	V03-0125-05	Transistor	2SC7	34 (Y)			
Q3	V01-0116-05	Transistor	2SA7	55 (C)			
Q4	V03-0343-05	Transistor	2SC1	419 (C)			
Q5	V01-0113-05	Transistor	2SA4	96 (Y)			
Q6~8	V03-0099-05	Transistor	2SC3	72 (Y)			
D1, 2	V11-0219-05	Diode	V06B				
D3	V11-0076-05	Diode	1815	55			
D4, 5	V11-0219-05	Diode	V06B				
D6	V11-0243-05	Diode	WZ-0	61			
	PO	TENTIOME	TER				
VR1	R12-0042-05	500Ω					
		COIL					
L1	L33-0025-05	Heater cho	ck 1μ	Н			
	MIS	SCELLANE	ous		-	<u> </u>	
_	F01-0114-04	Heat sink	x 2				
		<u> </u>				1	

AF/PS (X49-1090-00)

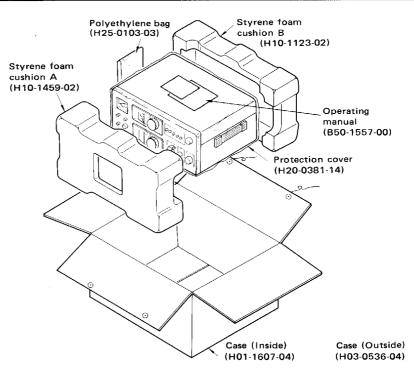
Ref. No.	Parts No.	Description			
		APACITOR			
C1	CK45B1H102K	Ceramic 0.001µF ± 10%			
C2	CE04W1HR47(RL)	Electrolytic 0.47µF 50WV			
C3	CE04W1C101(RL)	Electrolytic 100µF 16WV			
C4	CE04WoJ331	Electrolytic 330µF 6.3WV	1		
C5	CQ93M1H473K	Mylar 0.047μF ± 10%	1		
C6	CE04W1HR47(RL)	Electrolytic 0.47µF 50WV			
C7	CE04W1A470(RL)	Electrolytic 47µF 10WV	ŀ		
C8	CK45B1H471K	Ceramic 470pF ±10%			
C9	CE04W1C330(RL)	Electrolytic 33µF 16WV	1		
C10	CE04W1A221(RL)	Electrolytic 220µF 10WV	1		
C11	CE04W1A221(RL)	Electrolytic 220µF 10WV	-		
C12	CK45F1H103Z	Ceramic 0.01µF +80%,-20	%		
C14	CE04W1C101(RL)	Electrolytic 100μF 16WV			
		RESISTOR			
R1	PD14BY2E103J	Carbon 10k Ω ±5% 1/4W			
R2	PD14BY2E223J	Carbon 22k Ω ±5% 1/4W			
R3	PD14BY2E471J	Carbon 470 Ω ±5% 1/4W			
R4	PD14BY2E102J	Carbon 1k Ω ±5% 1/4W			
R5	PD14BY2E221J	Carbon 220 Ω ±5% 1/4W			
R6	PD14BY2E391J	Carbon 390 Ω ±5% 1/4W			
R7	PD14BY2E103J	Carbon 10k Ω ±5% 1/4W			
R8	PD14BY2E330J	Carbon 33 Ω ± 5% 1/4W			
R9	PD14BY2E471J	Carbon 470 Ω ±5% 1/4W			
R10	PD14BY2E221J	Carbon 220 Ω ±5% 1/4W			
R12	PD14BY2E221J	Carbon 220 Ω ±5% 1/4W			
R13,14	R92-0041-25	Metal plate 0.47 Ω			
R15	PD14BY2E683J	Carbon 68 k Ω ± 5 % $1/4$ W			
R16	PD14BY2E103J	Carbon 10k Ω ±5% 1/4W	- 1		
R17	PD14BY2E471J	Carbon 470 Ω ±5% 1/4W			
R18	PD14BY2E331J	Carbon 330 Ω ±5% 1/4W	1		
R19	PD14BY2E222J	Carbon 2.2k Ω ±5% 1/4W			
R20	PD14BY2E102J	Carbon 1k Ω ±5% 1/4W			
R21	PD14BY2E272J	Carbon 2.7k Ω ±5% 1/4W			
R22	PD14BY2E222J	Carbon 2.2k Ω ±5% 1/4W	1		

MARKER (X52-1060-00)

Ref. No.	Parts No.	Description m				
		CAPACITOR				
C2	CC45CH1H470J	Ceramic 47pF ±5%				
C3	CQ08S1H331J	Polystyrene 330pF ±5%				
C4	CC45CH1H101J	Ceramic 100pF ±5%				
C5	CK45F1H403Z	Ceramic 0.04µF +80%,—20%	,			
C6	CC35SL1H010C	Ceramic 1pF ± 0.25pF				
		RESISTOR				
R1	PD14BY2E221J	Carbon 220 Ω ±5% 1/4W				
R2	PD14BY2E104J	Carbon 100k Ω ±5% 1/4W	'			
R3	PD14BY2E103J	Carbon 10k Ω ±5% 1/4W	·			
R4	PD14BY2E105J	Carbon 1M Ω ±5% 1/4W	'			
R5	PD14BY2E102J	Carbon 1kΩ ±5% 1/4W	.			
	SE	MICONDUCTOR				
Q1, 2	V03-0079-05	Transistor 2SC460B				
	COIL/T	RIMMER/CRYSTAL				
L1	L40-1021-03	Ferri-inductor 1mH				
TC1	C05-0029-15	Ceramic trimmer 50pF				
X1	L77-0364-05	Quartz crystal 500kHz				
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	ı		i			

TROUBLESHOOTING/PACKING

Symptom	Condition	Service Point	Possible Cause	Remedy
1. The set is not energized.		1) Fuse 2) POWER switch 3) Power cord	Fuse bloken Switch malfunction Poor contact in leads and chassis	Check Check and modification
2. Lamps are not lit up.				In DC operation lamps are lit only if the LIGHT switch is depressed.
	Meter and dial lamps are not lit.	LIGHT switch Transformer wiring	Switch malfunctionDefective wiring	· Check · Check
3. Poor sensitivity	Noise cannot be heard either.	1) AF/PS unit 2) PHONE jack 3) Speaker connector	Q3,, Q4 defective Poor contact Poor contact	· Check · Check · Check
	· Noise can be heard.	1) AF/PS unit	Stabilized voltage insuf- ficient	· Check
		2) RF unit 3) Switch unit	 Q1 (3SK35) defective Filter defective Poor switch contact 	Voltage check Check Check
		4) IF unit	 AGC transistor defective 	Voltage check
		5) Coil pack unit	 Deviation from coil adjustment 	· Readjustment
	Sensitivity is defective only in band F.	1) RF unit	· Q4 (2SC460) defective	· Oscillation check
4. Meter does not deflect.		1) IF unit	Deviation in VR2 (S ZERO ADJ.) or associat- ed circuit	· Readjustment and check
	· Deflection is insuf- ficient	1) IF unit	Deviation in VR1 (S SENSE ADJ.) or asso- ciated circuit	· Readjustment and check
5. Abnormal oscillation occurs in the marker	· No oscillation	1) Marker unit	TC1 deviation or crystal defective	· Check
unit.	- Many beats are gener-	1) Marker unit	· Crystal defective	· Replacement
			· Excessive output	Reduction of C6 capacity



DIAL STRING ARRANGEMENTS

1. REPLACEMENT OF DIAL DRUM AND DIAL STRING ARRANGEMENT

(1) Dismantle Upper and Lower Cases

- a. The upper case has 8 bolts.
- b. The lower case has 13 bolts. Remove the DC battery cord plug which is attached to the lower case.

(2) Dismantle the Panel

- a. Remove 7 knobs from the front panel
- Remove each fixing bolt at right and left of the panel.
- c. Remove 2 fixing bolts respectively from right and left sides of the sub-panel. This widens the clearance between chassis and sub-panel.

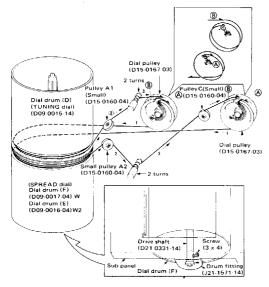
(3) Replace the Dial Drum

- a. Remove a string from the dial drum.
- b. Remove 3 bolts respectively from top and bottom hardware, used to support the dial drum.
- c. Loosen the center shaft stopper of the dial drum.
- d. Slowly draw out the dial drum from the center shaft, protecting the drum against damage.
- The dial drum can be mounted in the reverse order of the above.

2. STRING ARRANGEMENT FOR TUNING AND SPREAD DIALS

(1) Carefully refer to the drawing of the finished string arrangement to grasp the entire setting condition.

① Give one and half turns of a dial string around the pulley groove center toward you. Then, starting from the bottom groove of dial drum D, give 2 turns around the drum and hang it on small pulley A1.



String Arrangement for Tuning and Spread Dials

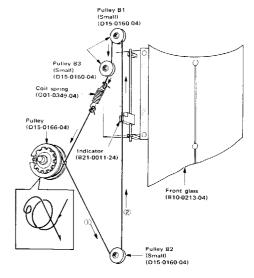
Stretch the string of small pulley A1 and give 2 turns around the pulley shaft, starting from bottom of hither side and finishing at thither side. Starting from the thither side, also give 2 turns around the dial pulley and join it with the other end of string.

SPREAD DIAL

- ① Give one and half turns of a dial string around the center groove of the dial pulley. Then, starting ffrom the upper groove of dial drum F (or E), give 2 turns around the drum and hang it on small pulley A2.
- Stretch the string of small pulley A2 and give 2 turns around the pulley shaft, starting from bottom of hither side and finishing at thither side. Then hang this string on small pulley C.
- Stretch the string of small pulley C and give 2 turns around the dial pulley, starting from top of hither side. Then connect it with the other end of string.

3. STRING ARRANGEMENT FOR BAND SELECTOR PULLEY

- ① Connect one end of spring with a string.
- ② As illustrated, give a single turn of string around the hollow part of the pulley, starting from the thither side. After giving another turn around the pulley, hang it on small pulley B2.
- Stretch the string from small pulley B2 and hang it on small pulley B1. Connect this string with the other end of spring. (The string knot at the end of spring should have moderate tightness not to permit loosening.)
- Hang the string on small pulley B3 to give proper tension.



String Arrangement for BAND Selector Pulley

TEST EQUIPMENT REQUIRED

(1) DC Valve Voltmeter

Input impedance

More than 100 $\text{M}\Omega$

(2) Oscilloscope

With sufficient sensitivity

(3) AF Valve Voltmeter

Measuring frequency Input impedance 50 Hz \sim 10 kHz More than 1 M Ω

(4) RF Valve Voltmeter

Measurable frequency

40 MHz

(5) SSG

Oscillating frequency ATT

170 kHz ~ 40 MHz

-20 dB ~ 120 dB

(6) Frequency Counter

Measurable frequency

More than 40 MHz

1. PRELIMINARY WORK

(1) Knob Setting

Unless otherwise specified, knobs should be set to the following positions:

RF GAIN

MAX

MODE

AM

ANL TONE OFF

SELEC

NORMAL

MARKER

WIDE

MARKER

OFF

(2) Connect an 8 Ω dummy load to EXT SP terminal.

(3) Power Supply Check

Prepare for the power supply of AC, 13.8V DC, and 12V DC (UM-1 \times 8 or equivalent).

- (i) Confirm that POWER SW is OFF. Connect respective sources to the AC cord, external DC cord, and internal battery terminal. Examine whether respective source voltages are correctly maintained.
- (ii) Set POWER SW to ON and confirm that the meter and dial lamps are lit.
- (iii) Set LIGHT SW to ON and confirm that the meter and dial lamps are turned dim.
- (iv) Pull out the AC cord with POWER SW set to ON and check whether the lamps go out. Also confirm that these lamps are lit at normal brightness when the LIGHT SW is depressed.
- (v) Pull out the DC cord further and depress LIGHT SW. Confirm that the meter and dial lamps dimly

at that time.

- (vi) Again, connect the AC cord only.
- (vii) Check the power supply voltage.
 - (a) 13.8V at socket terminal 9 of AF/PS unit
 - (b) 9.0V at socket terminal 5 of AR/PS unit If there is an extreme fluctuation from 9V, adjust VR1 of AF/PS unit until 9V is obtained.

2. IF CIRCUIT ADJUSTMENT

(1) Adjustment of IFT and OSC Coil in RF IF Unit

- (i) Adjust IFT of the RF IF unit to obtain the required bandwidth and also adjust the local oscillator of F BAND.
- (ii) Adjustment
 - (a) Set BAND selector SW to A \sim E BAND, with SELEC SW in WIDE setting.
 - (b) Apply SSG output (455 kHz) to MGI terminal of the RF unit so that the S meter deflects by about 5 graduations.
 - (c) When input signal is swept in SSG mode, the S meter deflection appears as illustrated in Fig. 1.
 - (d) Adjust T1 and T4 of the RF unit and T1 and T2 of the IF unit so that a maximum S meter deflection can be obtained at the adjusting point (lower side of f).
 - (e) Set BAND selector switch to F BAND and connect the RF valve voltmeter to G2 of the RF unit.
 - (f) Turn the T3 core of the RF unit and fix it in a position 1/2 turn withdrawn from the maximum output point (about 0.7V rms).
 - (g) Set the SSG signal frequency to 4.034 MHz and adjust T2 of the RF unit until the S meter deflection becomes maximum at the S meter peak on lower side of f, in the same manner as for (c).

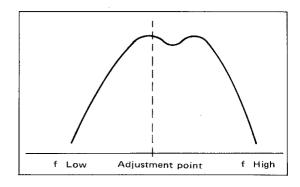


Fig. 1 S Meter Deflection

3. COIL PACK ADJUSTMENT (Table 1)

Adjust trimmer and coil of the coil pack in the following order to the graduation of dial frequency.

Secure required sensitivity and selectivity.

(i) Put the receiver so that the cursor line can be seen directly. Connect the AF valve voltmeter and oscilloscope to both ends of 8Ω dummy load, as illustrated in Fig. 2.

Receiver's knob setting positions are as follows:

- (a) MODE AM
- (b) SELEC NARROW
- (c) RF GAIN MAX
- (d) SPREAD DIAL 100°
- (ii) Adjustment should be started from 1.3 MHz of C BAND (because of rigorous sensitivity control). Set each knob to the maximum GAIN when inputting VR1 of RF unit to 1.3 MHz 6 dB and adjust it so that AF output is attained to 2V in AF, VR, MAX setting.
- (iii) Permissible frequency deviation at the tracking points should be such that the dial graduation end touches the edge of cursor line. (Repeat this adjustment 2 or 3 times.) Therefore, SSG should have been corrected in advance.
- (iv) In a high-frequency range of E ~ F BAND, care must be taken not to seize an image frequency. While signals are received by turning the dial of receiver, a higher frequency on the dial is the wanted one and a lower frequency is the image frequency. This relationship is reversed when the receiver dial is fixed and frequency tracing is effected in SSG mode.
- (v) All adjustments should be aimed to obtain peak deflections of S meter.
- (vi) Conditions for sensitivity measurement are SSG 1 kHz 30% in MODE-AM setting and 0.63V/8 Ω for MOD input and AF output. Each knob should be adjusted until maximum sensitivity is obtained.

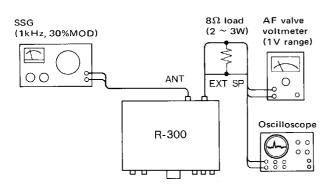


Fig. 2

4. BFO ADJUSTMENT

- (i) Set MODE SW to CW/SSB position and receive a signal (its frequency obtainable from previous adjustment). Obtain a maximum S meter deflection (S \sim 9 approximately) in SELEC NARROW setting.
- (ii) With the BFO knob set in the center, turn the T3 core of the IF unit through the adjusting hole of the rear panel and adjust it to a condition of zero beat.
- (iii) Turn the BFO knob to the right and left ends and confirm that the variation range is more than 2.5 kHz at both ends. If the variable range has deviated, check whether the knob is mounted correctly.

5. S METER ADJUSTMENT

- (i) Set RF GAIN to the minimum position and adjust S METER 0 ADJUST on the rear panel so that the S meter can be ready to start deflection at the left end of the scale.
- (ii) Set the receiver to D BAND (5 MHz) and the SELEC knob to NARROW position. Then apply unmodulated signal of about 20 dB from SSG and adjust respective knobs to the maximum sensitivity.
- (iii) Adjust semi-solid resistor VR1 of the IF unit so that a deflection of the S meter can be S-9 at that time.
- (iv) Confirm that SSB outputs for maintaining S-9 are respectively adjacent to the following values in the center frequency of each band. However, these values are merely for reference.

BAND	Frequency	SSG ATT
Α	280 kHz	8 dB
В	900 kHz	10 dB
С	2.0 MHz	14 dB
D	5.0 MHz	20 dB
E	12.0 MHz	26 dB
F	24.0 MH∠	21 dB

6. MARKER ADJUSTMENT AND OPERATION CHECK

- (i) Connect a counter to the MKO terminal of marker unit. If a coaxial cable for ANT input is left connected to this MKO terminal at that time, counter's input level is lowered and counting is impossible. Therefore the coaxial cable should be disconnected in this case.
- (ii) Adjust TC1 of the marker unit so that marker's oscillating frequency attains 500,000 Hz.
- (iii) Connect the coaxial cable for ANT input.
- (iv) Set the BAND selector SW to F BAND and receive marker signal at 19 MHz. Confirm that the S meter deflection is more than S-9 when each knob is adjusted to the maximum sensitivity.

1 Adjustment is conducted in accordance with the chart for tracking adjustment.

BAND	SSG & DIAL	SSG ATT (dB)	ANT TRIM position or output standard	No.	Adjustment point		Remarks
-64	1.3 MHz	*1	To the center	34	L 15	OSC-C coil	*1 Adjust SSG ATT until S meter deflec-
				35	L 3	ANT-C coil	tion amounts to $5 \sim 6$ graduations.
				36	L 9	RF-C coil	1
	2.8 MHz	1		37	Tc 9	OSC-C trimmer	*2 If ANT TRIM peak cannot be obtained
С	2.0 11112			38	Tc 3	<u> </u>	for No. 39, move L3 slightly to the left.
Ū	ļ		*2	39		ANT TRIM to peak.	1
	1.3 MHz 2.0 MHz 2.8 MHz	9 4 4	S/N ratio more than 10 dB		1 .	*	34 ~ 39 2 or 3 times in accordance with The RF unit need not be adjusted.
	3.4 MHz	*1	2 graduations from	_1_	L16	OSC-D coil	*1 Adjust SSG ATT until S meter deflec-
			center to left	2	L4	ANT-D coil	tion amounts to 5 \sim 6 graduations.
				3	L10	RF-D coil	
	7.0 MHz	1		4	Tc10	OSC-D trimmer	*2 If ANT TRIM peak cannot be obtained
D				5	Tc 4	RF-D trimmer	for No. 6, move L4 slightly to the left.
			*2	6	Adjust	ANT TRIM to peak.	1
	3.4 MHz 5.0 MHz 7.0 MHz	9 6 6	S/N ratio more than 10 dB	7	is obta still ins is met	ined and sensitivity s sufficient, turn VR1 o	ents 2 or 3 times until correct dial frequency standard (at left) is satisfied. If sensitivity is of the RF unit until the standard requirement at to a point slightly before saturation of AF put.)
	8.0 MHz	*1	To the center	8	L17	OSC-E coil	*1 Adjust SSG ATT until S meter deflec-
	0.0 101172	'	To the conter	9	L 5	ANT-E coil	tion amounts to $5 \sim 6$ graduations.
				10	L11	RF-E coil	
	17 MHz	-		11	Tc11		*2 If ANT TRIM peak cannot be obtained
_	17 MHZ				Tc 5		
E			*2	12		RF-E trimmer ANT TRIM to peak.	for No. 13, move L5 slightly to the left.
	8.0 MHz 12 MHz 17 MHz 19 MHz	14 9 9 *1	S/N ratio more than 10 dB	14 15 16 17 18		nents for BAND D.	 . 8 ~ 13 2 or 3 times in accordance with VR1 of RF unit need not be adjusted. *1 Adjust SSG ATT until S meter deflection amounts to 5 ~ 6 graduations. *2 If ANT TRIM peak cannot be obtained
F				19	Tc 6	RF-F trimmer	for No. 20, move L6 slightly to the left.
			*2	20	Adjus	t ANT TRIM to peak.	
	19 MHz 24 MHz 29 MHz	14 9 6	S/N ratio more than 10 dB	21		-	15 ~ 20 2 or 3 times in accordance with VR1 of RF unit need not be adjusted.
	190 kHz	*1	Move the variable	22	L 13	OSC-A coil	*1 Adjust SSG ATT until S meter deflec-
			condenser fully to	23	L 1	ANT-A coil	tion amounts to $5 \sim 6$ graduations.
			the right.	24	L 7	RF-A coil	7
Α	380 kHz	-		25	Tc 7	OSC-A trimmer	*2 ANT TRIM is not used.
		1		26	Tc 1	RF-A trimmer	1
			*2		1 .	1	1
	190 kHz 280 kHz 380 kHz	9 6 6	S/N ratio more than 10 dB	27	adjustr	ments ofor BAND D.	22 ~ 26 2 or 3 times in accordance with VR1 of RF unit need not be adjusted.
	600 kHz	*1	Move tha variable	28	L 14		*1 Adjust SSG ATT until S meter deflec-
			condenser fully to	29	L 2	ANT-B coil	tion amounts to $5 \sim 6$ graduations.
			the right.	30	L 8	RF-B coil	
В	1200 kHz	7	-	31	Tc 8	OSC-B trimmer	*2 ANT TRIM is not used.
-				32	Tc 2	RF-B trimmer	
	600 kHz 900 kHz 1200 kHz	9 4 4	S/N ratio more than 10 dB	33	Repea	t adjustments of No.	. 29 ~ 32 2 or 3 times in accordance with VR1 of RF unit need not be adjusted.

Table 1

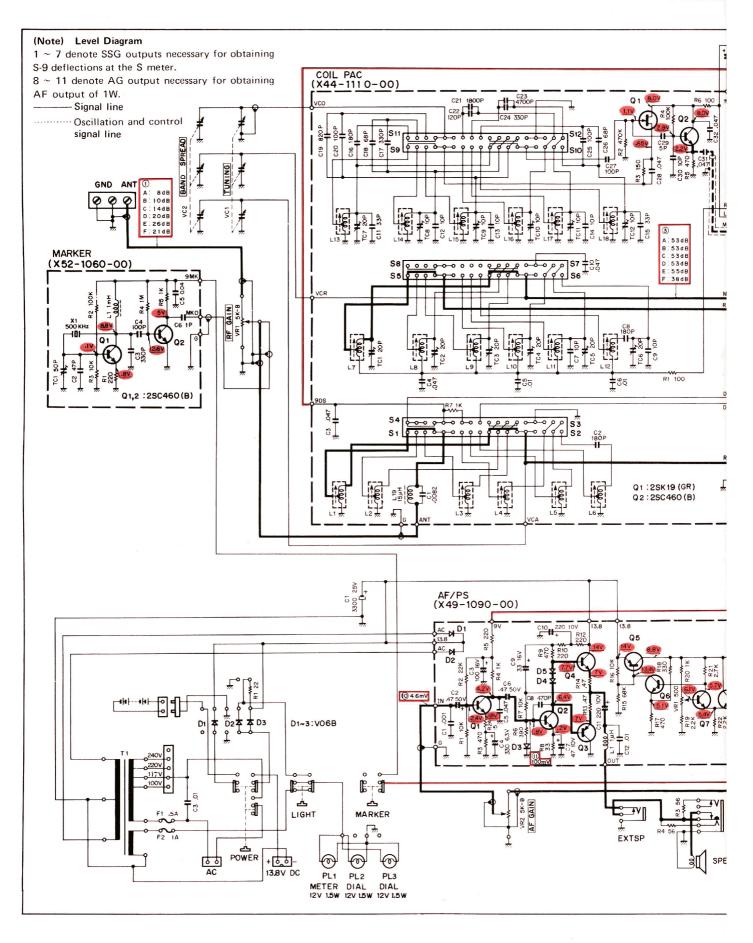
7. ANL OPERATION CHECK

- (i) Connect SSG and noise generator to the ANT terminal of receiver. Set MODE SW to AM and receive a proper AM signal from SSG.
- (ii) Switch on the noise generator and impose a noise signal on the AM signal.
- (iii) Set ANL to ON watching at the oscilloscope. Confirm that the noise peak level is limited at that time.
- (iv) Switch off the noise generator and set ANL from OFF to ON. Confirm that the output level is lowered by 10 dB or less at that time.

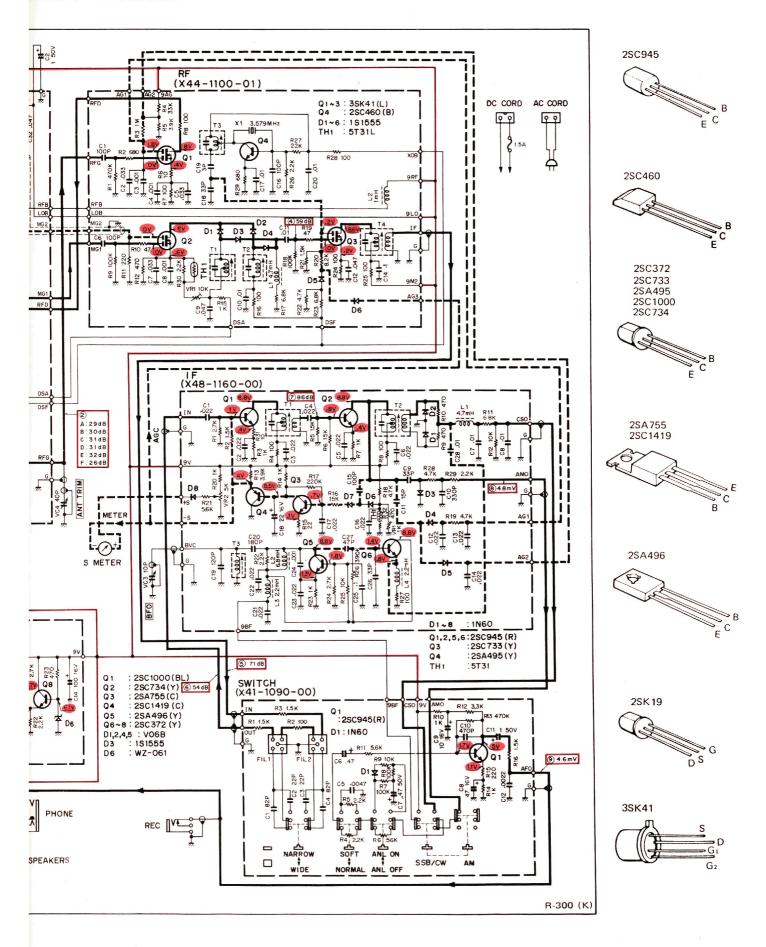
8. TONE CHECK

- (i) Apply an AM signal of 1 kHz 30% modulation to the receiver (TONE to be set to NORMAL).
- (ii) Confirm that the output level is lowered by 6 dB or less when TONE SW is set to SOFT.

SCHEM



MATIC DIAGRAM



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